

Green Products

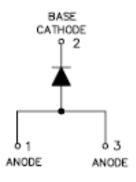
50WQ10FN SCHOTTKY RECTIFIER

Applications:

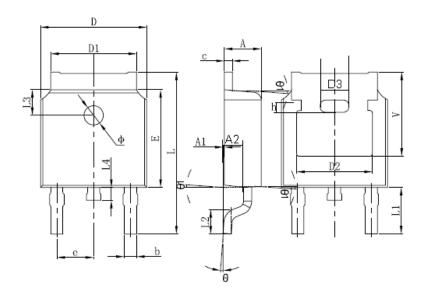
- Disk drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery charging

Features:

- 150 °C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm / Inches



Dimensions	in Millimeters	0.087 0.0 0.000 0.0 0.028 0.0 0.018 0.0 0.256 0.2 0.202 0.2 0.236 0.2 0.386 0.4 0.114 REF. 0.055 0.0 0.063 REF. 0.024 0.0 0.043 0.0 0.043 0.0 0.07 8 0.036 0.0 0.211 REF. 0.070REF.	s in inches
Min.	Max.	Min.	Max.
2.200	2.380	0.087	0.094
0.000	0.100	0.000	0.004
0.710	0.810	0.028	0.032
0.460	0.560	0.018	0.022
6.500	6.700	0.256	0.264
5.130	5.460	0.202	0.215
4.830	REF.	0.190	REF.
6.000	6.200	0.236	0.244
2.186	2.386	0.086	0.094
9.800	10.400	0.386	0.409
2.900	REF.	0.114	REF.
1.400	1.700	0.055	0.067
1.600	REF.	0.063	REF.
0.600	1.000	0.024	0.039
1.100	1.300	0.043	0.051
0°	8°	0°	8°
0.910	1.110	0.036	0.044
5.350 REF.		0.211	REF.
1.778	REF.	0.070	REF.
0.762	REF.	0.030	REF.
7°		7	•
	Min. 2.200 0.000 0.710 0.460 6.500 5.130 4.830 6.000 2.186 9.800 2.900 1.400 0.600 1.100 0* 0.910 5.350 1.778	2.200 2.380 0.000 0.100 0.710 0.810 0.460 0.560 6.500 6.700 5.130 5.460 4.830 REF. 6.000 6.200 2.186 2.386 9.800 10.400 2.900 REF. 1.400 1.700 1.600 REF. 0.600 1.000 1.100 1.300 0° 8° 0.910 1.110	Min. Max. Min. 2 200 2.380 0.087 0.000 0.100 0.000 0.710 0.810 0.028 0.460 0.560 0.018 6.500 6.700 0.256 5.130 5.460 0.202 4.830 REF. 0.190 6.000 6.200 0.236 2.186 2.386 0.086 9.800 10.400 0.386 2.900 REF. 0.114 1.400 1.700 0.055 1.600 REF. 0.063 0.600 1.000 0.024 1.1100 1.300 0.043 0* 8* 0* 0.910 1.110 0.036 5.350 REF. 0.211 1.778REF. 0.070 0.762REF. 0.030

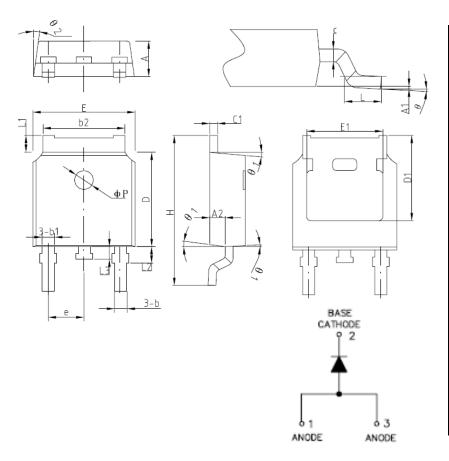
OPTION 1(CJ)

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •





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SYMBOL	MIN.	TYP.	MAX.		
Α	2.20	2.30	2.38		
A1	0	-	0.10		
	_				
A2	0.90	1.01	1.10		
b	0.71	0.76	0.86		
b1		0.76			
b2	5.13	5.33	5.46		
С	0.47	0.50	0.60		
c1	0.47	0.50	0.60		
D	6.0	6.10	6.20		
D1	-	5.30	-		
E	6.50	6.60	6.70		
E1	-	4.80	-		
е		2.286BSC			
Н	9.70	10.10	10.40		
L	1.40	1.50	1.70		
L1	0.90	-	1.25		
L2		1.05			
L3		0.8			
ФР	_	1.2			
Θ	0°	-	8°		
Θ1	5°	7°	9°		
Θ2	5°	7°	9°		

OPTION 2(HD)

DPAK

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Marking Diagram:



Where XXXXX is YYWWL

= Forward Current (5A)

W = Configuration Q = Device Type

10 = Reverse Voltage (100V)

FN = Package type

SSG = SSG YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
50WQ10FN	DPAK (Pb-Free)	2500 pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}{c} \egin{array}$	-	100	V
Average Forward Current (per device)	I _{F(AV)}	50% duty cycle @T _C = 135°C, rectangular wave form	5.5	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	130	Α

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 5A, Pulse, T _J = 25 °C	0.75	0.77	V
	V _{F1}	@ 10A, Pulse, T _J = 25 °C	0.85	0.91	V
	V_{F2}	@ 5 A, Pulse, T _J = 125 °C	0.61	0.63	\/
	V _{F2}	@ 10 A, Pulse, T _J = 125 °C	0.72	0.74	V
Reverse Current *		$@V_R = rated V_R$	0.002	1.00	mA
	I _{R1}	T _J = 25 °C	0.002	1.00	IIIA
	L	$@V_R = rated V_R$	0.4	4	mA
	I _{R2}	T _J = 125 °C	0.4	4	ША
Junction Capacitance	C_T	$@V_R = 5V, T_C = 25 ^{\circ}C$	180	250	pF
	OT	$f_{SIG} = 1MHz$	100	250	Рі
Typical Series Inductance	L _S	Measured lead to lead 5	5.0	_	nН
	ĽS	mm from package body	5.0	_	1111
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

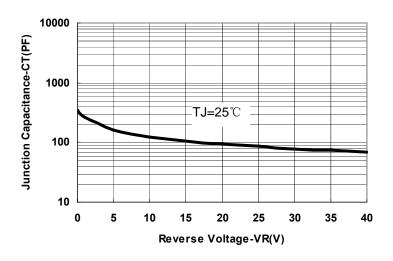
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	Ô
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (per leg)	$R_{ hetaJC}$	DC operation	3.0	°C/W
Approximate Weight	wt	-	0.32	g
Case Style	DPAK			

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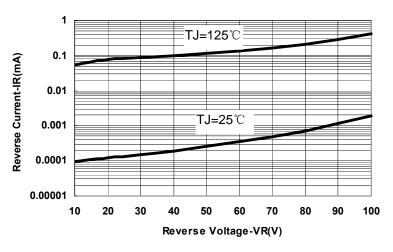


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

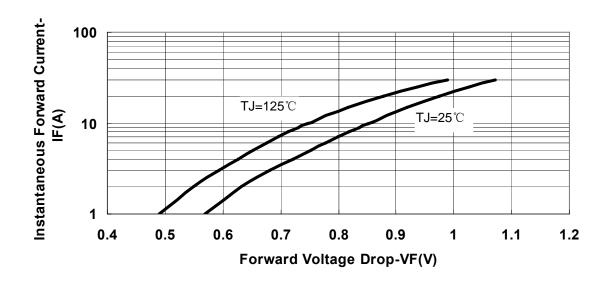


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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